TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

# TA75060P

### SINGLE OPERATIONAL AMPLIFIER

The TA75060P is a J-FET input low-power operational amplifier with low input bias and offset current, fast slew rate. The TA75060P is pin compatible with the TA7506P. The TA75060P is an excellent choice for active filters, integrators, buffers and sample-and-hold circuits.

#### **FEATURES**

Low Supply Current : 250μA MAX. Low Input Bias Current : 400pA MAX. Low Input Offset Current : 200pA MAX.

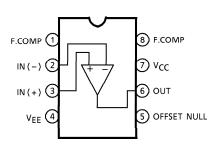
High Slew Rate :  $3.5V / \mu s (A_V = 1)$ 

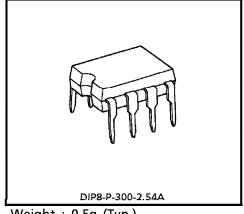
Wide Supply Voltage Range :  $\pm 2 \sim \pm 18V$ 

**Output Short Circuit Protection** 

Offset Null Capability

#### PIN CONNECTION (TOP VIEW)





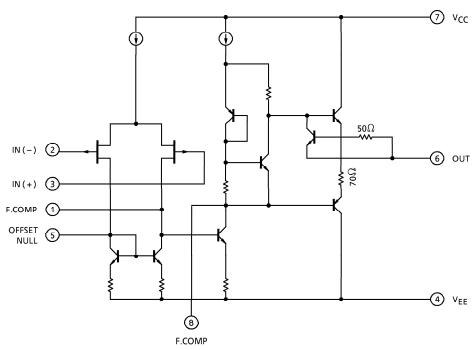
Weight: 0.5g (Typ.)

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- operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

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### **EQUIVALENT CIRCUIT**



### **MAXIMUM RATINGS** (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V <sub>C</sub> C	18	V
Supply Voltage	VEE	<b>–</b> 18	V
Differential Input Voltage	DVIN	± 30	V
Input Voltage	VIN	± 15	V
Power Dissipation	PD	500	mW
Operating Temperature	T <sub>opr</sub>	<b>- 40∼85</b>	°C
Storage Temperature	T <sub>stg</sub>	<b>- 55∼125</b>	°C

## **ELECTRICAL CHARACTERISTICS** ( $V_{CC} = 15V$ , $V_{EE} = -15V$ , Ta = 25°C)

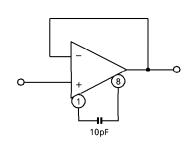
CHARACTERISTIC	SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Offset Voltage	V <sub>IO</sub>	_	$R_g \le 10 k\Omega$	_	3	15	mV
TC Of Input Offset Voltage	TCV <sub>IO</sub>	_	_	_	10	_	μ <b>V</b> / °C
Input Offset Current	lo	_	_	_	5	200	pΑ
Input Bias Current	Ц	_	_	_	30	400	pА
Common Mode Input Voltage	CMVIN	_	_	± 11.5	± 12	_	V
Maximum Output Voltage	Vом	<u> </u>	$R_L = 10k\Omega$	20	27	_	V <sub>p-p</sub>
Voltage Gain (Open Loop)	GV		$V_{OUT} = \pm 10V$ , $R_L = 10k\Omega$	3	6	_	V/mV
Unity Gain Cross Frequency	f <sub>T</sub>	_	Open Loop, $R_L = 10k\Omega$	_	1	_	MHz
Input Resistance	R <sub>IN</sub>	_	_	_	10 <sup>12</sup>	_	Ω
Common Mode Input Signal Rejection Ratio	CMRR	_	$R_g \le 10 k\Omega$	70	76	_	dB
Supply Voltage Rejection Ratio	SVRR	_	$R_g \le 10 k\Omega$	70	76	_	dB
Supply Current	ICC, IEE	_	Non load	_	200	250	μΑ

### **OPERATING CHARACTERISTICS** ( $V_{CC} = 15V$ , $V_{EE} = -15V$ , Ta = 25°C)

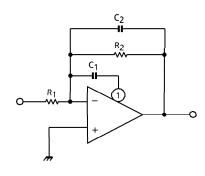
CHARACTERISTIC	SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Slew Rate	SR	_	$V_{IN} = 10V_{p-p}$ , $R_L = 10k\Omega$ , $C_L = 100pF$ , $A_V = 1$	-	3.5	_	<b>V</b> / μ <b>s</b>
Equivalent Input Noise Voltage	V <sub>NI</sub>	_	$R_S = 100\Omega$ , $f = 1kHz$	I	42	_	nV /√Hz

### TYPICAL APPLICATION

#### (1) UNITY-GAIN BUFFER



# (3) FEED FORWARD COMPENSATION

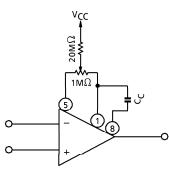


$$C_1 = 500pF$$

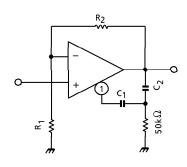
$$C_2 = \frac{1}{2\pi f_0 R_2}$$

$$f_0 \approx 1MHz$$

### (2) OFFSET NULL CIRCUIT



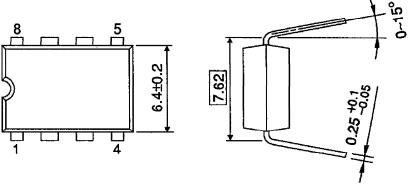
### (4) TOW POLE COMPENSATION

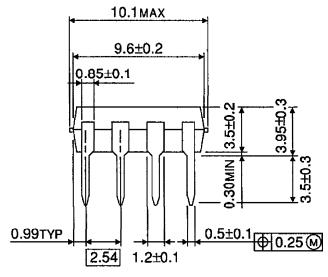


$$C_1 > \frac{R_1}{R_1 + R_2} C_S$$
  
 $C_S = 10pF$   
 $C_2 = 10C_1$ 

Unit: mm

## **OUTLINE DRAWING** DIP8-P-300-2.54A





Weight: 0.5g (Typ.)